

RT Synthesis of Air-Stable and Size-Tunable Luminescent ZnS coated Cd₃P₂ Nanocrystals with High Quantum Yields

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Abstract

The high temperatures usually required for the synthesis of quantum dots (QDs) are a major drawback, which, beyond obvious energetic concerns, represents a significant limit in the implementation of simple “routine” synthesis methods to ensure run-to-run reproducibility, automation possibilities, and standardization of the nanomaterials. Synthetic protocol to cadmium phosphide QDs, which is a conspicuous material by virtue of its ability to absorb and emit in the near infrared wavelength window (narrow bandgap -0.55 eV- and large excitonic radius -18 nm) also suffer from this major limitation ($T > 250^{\circ}\text{C}$).^[1,2] We will show how the design of a suitable precursor allows breaking this technological limitation and allows the room temperature synthesis of air-stable, size-tunable, and high optical quality (quantum yields > 50%) Cd₃P₂/ZnS QDs.^[3] A large range of emissivity is easily covered (from ~600 nm to 1400 nm) thanks to the modulation of the concentration of reactants and of the temperature (30°C, 90°C). The strategy followed to achieve this two steps synthesis at low temperature is based on the choice and design of highly reactive and soluble precursors, Cd(OAc)₂(OAm)₂ (OAc = acetate, OAm = octylamine) and (TMS)₃P (tris(trimethylsilyl)phosphine) for the formation of the Cd₃P₂ cores and Zn(OAc)₂(OAm)₂ and C₂H₄S (ethylene sulphide) for the coating process. ¹H, ¹³C and ³¹P solution and solid-state NMR studies will be presented and show the presence of a thin layer of oxide at the interface Cd₃P₂/ZnS and of tightly bond ligands (acetate and octylamine) at the surface of the QDs.

References

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Figures

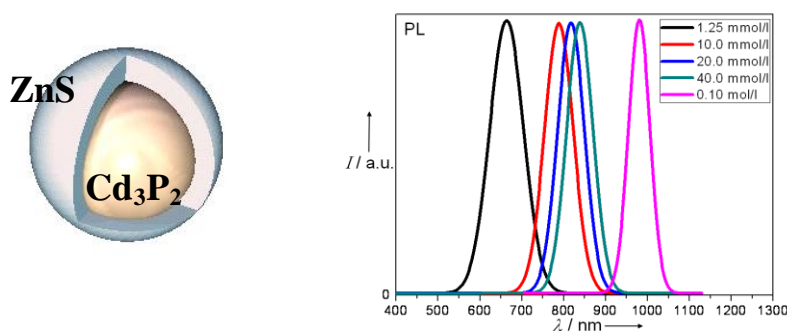


Fig.1 Concentration effect on the PL emissivity of core/shell Cd₃P₂/ZnS QDs